NSN 5962-01-071-6651

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-071-6651 **Body Length:** Between 0.870 inches and 0.910 inches **Body Width:** Between 0.250 inches and 0.300 inches **Body Height:** Between 0.140 inches and 0.170 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and electrostatic sensitive and expandable and low power and w/decoded output and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 18 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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